

## 74ABT125 Quad Buffer with 3-STATE Outputs

### General Description

The ABT125 contains four independent non-inverting buffers with 3-STATE outputs.

### Features

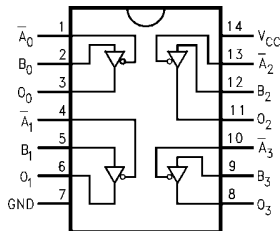
- Non-inverting buffers
- Output sink capability of 64 mA, source capability of 32 mA
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability
- Disable time less than enable time to avoid bus contention

### Ordering Code:

Order Number	Package Number	Package Description
74ABT125CSC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
74ABT125CSJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ABT125CMTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

### Connection Diagram



### Pin Descriptions

Pin Names	Descriptions
$\bar{A}_n, B_n$	Inputs
$O_n$	Outputs

### Function Table

Inputs		Output
$A_n$	$B_n$	$O_n$
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level  
L = LOW Voltage Level  
Z = HIGH Impedance  
X = Immaterial

Absolute Maximum Ratings (Note 1)		Recommended Operating Conditions					
Storage Temperature	-65°C to +150°C	Free Air Ambient Temperature	-40°C to +85°C				
Ambient Temperature under Bias	-55°C to +125°C	Supply Voltage	+4.5V to +5.5V				
Junction Temperature under Bias	-55°C to +150°C	Minimum Input Edge Rate ( $\Delta V/\Delta t$ )					
V <sub>CC</sub> Pin Potential to Ground Pin	-0.5V to +7.0V	Data Input	50 mV/ns				
Input Voltage (Note 2)	-0.5V to +7.0V	Enable Input	20 mV/ns				
Input Current (Note 2)	-30 mA to +5.0 mA						
Voltage Applied to Any Output in the Disabled or Power-Off State	-0.5V to 5.5V						
in the HIGH State	-0.5V to V <sub>CC</sub>						
Current Applied to Output in LOW State (Max)	twice the rated I <sub>OL</sub> (mA)						
DC Latchup Source Current (Across Comm Operating Range)	-300 mA						
Over Voltage Latchup (I/O)	10V						
<p><b>Note 1:</b> Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.</p> <p><b>Note 2:</b> Either voltage limit or current limit is sufficient to protect inputs.</p>							
DC Electrical Characteristics							
Symbol	Parameter	Min	Typ	Max	Units	V <sub>CC</sub>	Conditions
V <sub>IH</sub>	Input HIGH Voltage				V		Recognized HIGH Signal
V <sub>IL</sub>	Input LOW Voltage			0.8	V		Recognized LOW Signal
V <sub>CD</sub>	Input Clamp Diode Voltage			-1.2	V	Min	I <sub>IN</sub> = -18 mA
V <sub>OH</sub>	Output HIGH Voltage	2.5			V	Min	I <sub>OH</sub> = -3 mA
		2.0			V	Min	I <sub>OH</sub> = -32 mA
V <sub>OL</sub>	Output LOW Voltage			0.55	V	Min	I <sub>OL</sub> = 64 mA
I <sub>IH</sub>	Input HIGH Current			1	μA	Max	V <sub>IN</sub> = 2.7V (Note 3)
				1	μA	Max	V <sub>IN</sub> = V <sub>CC</sub>
I <sub>BVI</sub>	Input HIGH Current Breakdown Test			7	μA	Max	V <sub>IN</sub> = 7.0V
I <sub>IL</sub>	Input LOW Current			-1	μA	Max	V <sub>IN</sub> = 0.5V (Note 3)
				-1	μA	Max	V <sub>IN</sub> = 0.0V
V <sub>ID</sub>	Input Leakage Test				V	0.0	I <sub>ID</sub> = 1.9 μA, All Other Pin Grounded
I <sub>OZH</sub>	Output Leakage Current			10	μA	0-5.5V	V <sub>OUT</sub> = 2.7V; $\overline{OE}_n$ = 2.0V
I <sub>OZL</sub>	Output Leakage Current			-10	μA	0-5.5V	V <sub>OUT</sub> = 0.5V; $\overline{OE}_n$ = 2.0V
I <sub>OS</sub>	Output Short-Circuit Current			-275	mA	Max	V <sub>OUT</sub> = 0.0V
I <sub>C EX</sub>	Output HIGH Leakage Current			50	μA	Max	V <sub>OUT</sub> = V <sub>CC</sub>
I <sub>ZZ</sub>	Bus Drainage Test			100	μA	0.0	V <sub>OUT</sub> = 5.5V; All Others GND
I <sub>C CH</sub>	Power Supply Current			50	μA	Max	All Outputs HIGH
I <sub>C CL</sub>	Power Supply Current			15	mA	Max	All Outputs LOW
I <sub>C CZ</sub>	Power Supply Current			50	μA	Max	$\overline{OE}_n$ = V <sub>CC</sub> ; All Others at V <sub>CC</sub> or Ground
I <sub>C CT</sub>	Additional I <sub>CC</sub> /Input Outputs Enabled Outputs 3-STATE Outputs 3-STATE			1.5	mA	Max	V <sub>I</sub> = V <sub>CC</sub> - 2.1V
				1.5	mA		Enable Input V <sub>I</sub> = V <sub>CC</sub> - 2.1V
				50	μA		Data Input V <sub>I</sub> = V <sub>CC</sub> - 2.1V All Others at V <sub>CC</sub> or Ground
I <sub>C CD</sub>	Dynamic I <sub>CC</sub> (Note 3)	No Load		0.1	mA/ MHz	Max	Outputs Open $\overline{OE}_n$ = GND, (Note 4) One Bit Toggling, 50% Duty Cycle
<p><b>Note 3:</b> Guaranteed, but not tested.</p> <p><b>Note 4:</b> For 8 bits toggling, I<sub>CCD</sub> &lt; 0.8 mA/MHz.</p>							

## AC Electrical Characteristics

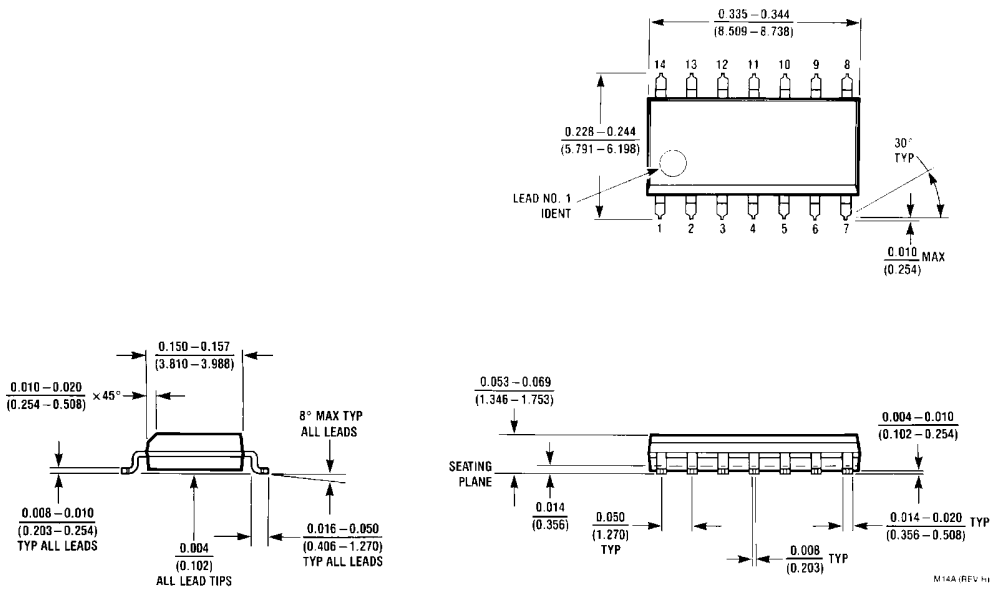
Symbol	Parameter	T <sub>A</sub> = +25°C V <sub>CC</sub> = +5V C <sub>L</sub> = 50 pF			T <sub>A</sub> = -40°C to +85°C V <sub>CC</sub> = 4.5V–5.5V C <sub>L</sub> = 50 pF		Units
		Min	Typ	Max	Min	Max	
t <sub>PLH</sub>	Propagation Delay	1.0		4.6	1.0	4.6	ns
t <sub>PHL</sub>	Data to Outputs	1.0		4.9	1.0	4.9	
t <sub>PZH</sub>	Output Enable	1.0		5.1	1.0	5.1	ns
t <sub>PZL</sub>	Time	1.0		6.8	1.0	6.8	
t <sub>PHZ</sub>	Output Disable	1.0		6.2	1.0	6.2	ns
t <sub>PLZ</sub>	Time	1.0		5.5	1.0	5.5	

## Capacitance

Symbol	Parameter	Typ	Units	Conditions T <sub>A</sub> = 25°C
C <sub>IN</sub>	Input Capacitance	5.0	pF	V <sub>CC</sub> = 0V
C <sub>OUT</sub> (Note 5)	Output Capacitance	9.0	pF	V <sub>CC</sub> = 5.0V

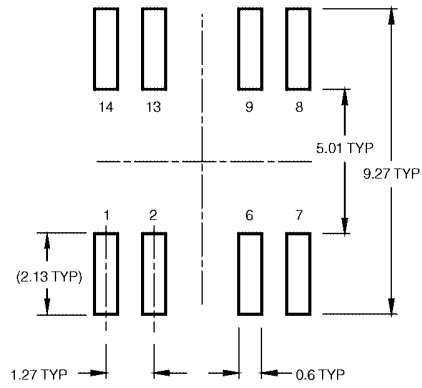
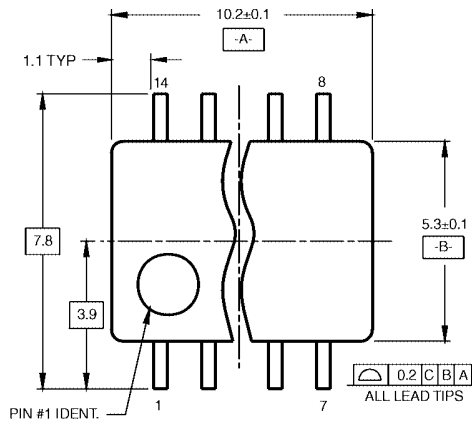
**Note 5:** C<sub>OUT</sub> is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.

**Physical Dimensions** inches (millimeters) unless otherwise noted

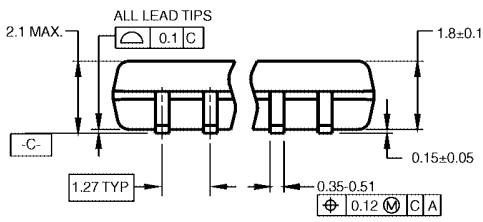


**14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body  
Package Number M14A**

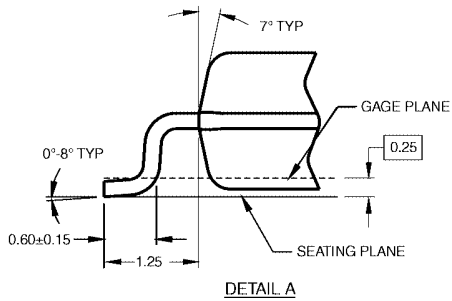
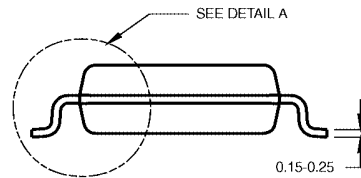
**Physical Dimensions** inches (millimeters) unless otherwise noted (Continued)



LAND PATTERN RECOMMENDATION



DIMENSIONS ARE IN MILLIMETERS

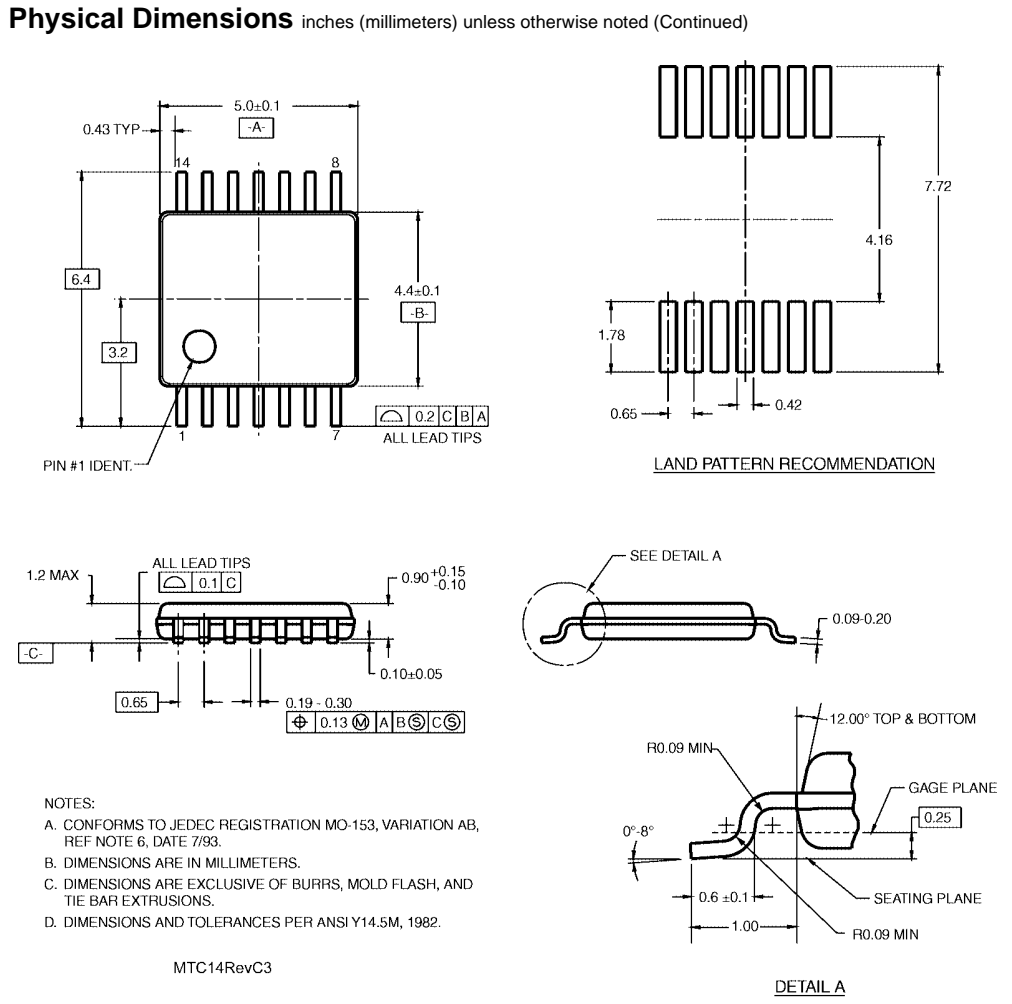


DETAIL A

- NOTES:
- A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.
  - B. DIMENSIONS ARE IN MILLIMETERS.
  - C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M14DRRevB1

**14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide Package Number M14D**



Fairchild does not assume any responsibility for use of any circuitry described, no circuit patent licenses are implied and Fairchild reserves the right at any time without notice to change said circuitry and specifications.

**LIFE SUPPORT POLICY**

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

[www.fairchildsemi.com](http://www.fairchildsemi.com)